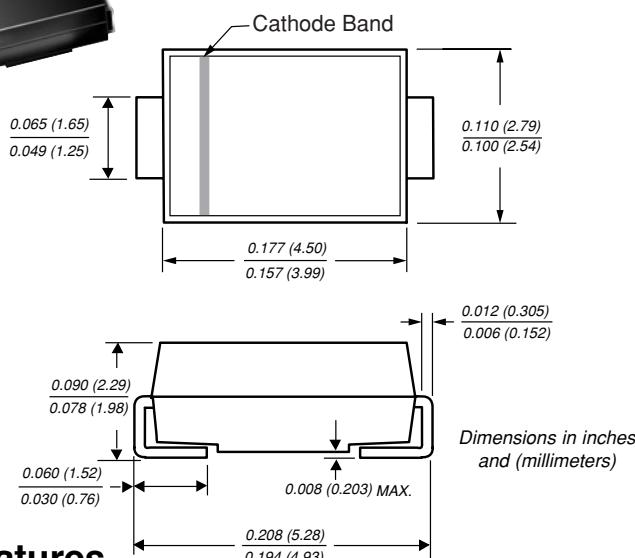
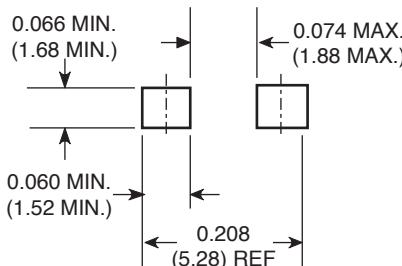


High-Current Density Surface Mount Schottky Rectifier


DO-214AC (SMA)

 Reverse Voltage 30 & 40 V
 Forward Current 2.0 A

Mounting Pad Layout

Features

- Low power loss, high efficiency
- Low profile surface mount package
- Built-in strain relief
- For use in low voltage high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0

Mechanical Data
Case: JEDEC DO-214AC molded plastic body

Terminals: Solder plated, solderable per MIL-STD750, Method 2026

 High temperature soldering guaranteed:
 250°C/10 seconds at terminals

Polarity: Color band denotes cathode end

Weight: 0.002 ounce, 0.064 gram

Maximum Ratings and Thermal Characteristics (TA = 25°C unless otherwise noted)

Parameter	Symbol	SSA23L	SSA24	Unit
Device marking code		23L	S24	V
Maximum repetitive peak reverse voltage	V _{RRM}	30	40	V
Maximum RMS voltage	V _{RMS}	21	28	V
Maximum DC blocking voltage	V _{DC}	30	40	V
Maximum average forward rectified current at TL (See Fig. 1)	I _{F(AV)}		2.0	A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}		60	A
Non-repetitive avalanche energy at TA = 25°C, IAS = 1.5A, L = 10mH	EAS		11.25	mJ
Typical thermal resistance ⁽²⁾	R _{θJA} R _{θJL}		110 28	°C/W
Voltage rate of change (rated V _R)	dv/dt		10,000	V/μs
Operating junction temperature range	T _J		-65 to + 150	°C
Storage temperature range	T _{STG}		-65 to + 150	°C

Electrical Characteristics (TA = 25°C unless otherwise noted)

Parameter	Symbol	Typ.	Max.	Typ.	Max.	Unit
Maximum instantaneous forward voltage at 2.0A ⁽¹⁾	V _F T _J =25°C T _J =125°C	0.43 0.32	0.45 0.38	0.45 0.36	0.49 0.42	V
Maximum DC reverse current at rated DC blocking voltage ⁽¹⁾	I _R T _J =25°C T _J =125°C	— 15	0.5 25	— 12	0.2 20	mA

 Notes: (1) Pulse test: 300μs pulse width, 1% duty cycle
 (2) Aluminum substrate mounted

SSA23L and SSA24



Vishay Semiconductors
formerly General Semiconductor

Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 – Forward Current Derating Curve

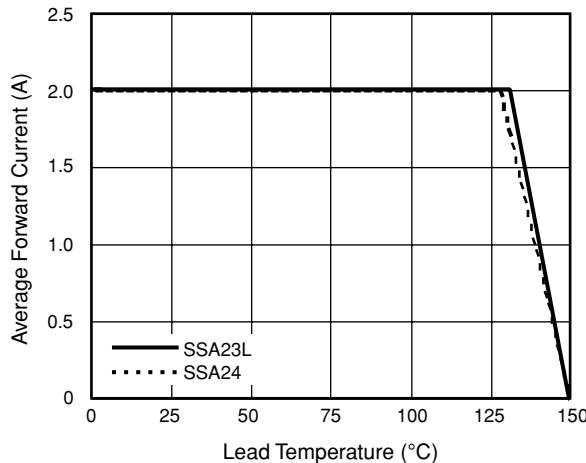


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

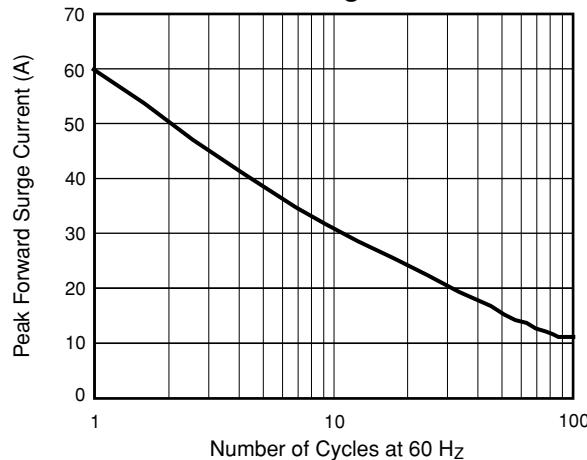


Fig. 3 - Typical Instantaneous Forward Characteristics

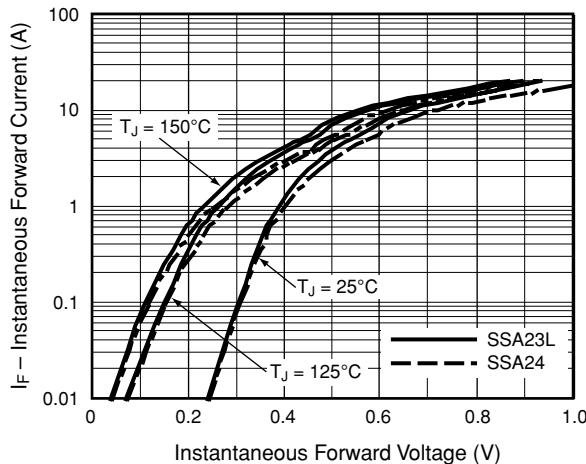


Fig. 4 - Typical Reverse Characteristics

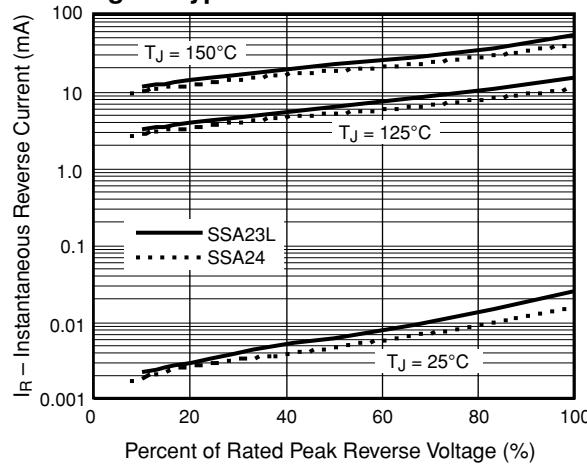


Fig. 5 - Typical Junction Capacitance

